

NPN SILICON RF POWER TRANSISTOR

DESCRIPTION:

The **ASI BLW32** is Designed for
Television Band IV & V
Applications up to 860 MHz.

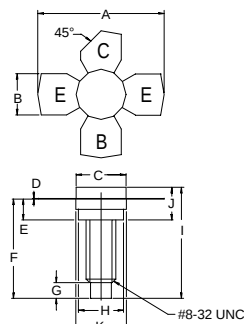
FEATURES:

- Common Emitter
- $P_G = 11$ dB at 0.5 W/ 860 MHz
- **Omnigold™** Metalization System

MAXIMUM RATINGS

I_C	1.0 A
V_{CBO}	50 V
V_{CEO}	30 V
V_{EBO}	4.0 V
P_{DISS}	10.8 W @ $T_C = 25^\circ\text{C}$
T_J	-65°C to $+200^\circ\text{C}$
T_{STG}	-65°C to $+150^\circ\text{C}$
θ_{JC}	16 $^\circ\text{C/W}$

PACKAGE STYLE .280 4L STUD



DIM	MINIMUM inches / mm	MAXIMUM inches / mm
A	1.010 / 25.65	1.055 / 26.80
B	.220 / 5.59	.230 / 5.84
C	.270 / 6.86	.285 / 7.24
D	.003 / 0.08	.007 / 0.18
E	.117 / 2.97	.137 / 3.48
F	.572 / 14.53	
G	.130 / 3.30	
H	.245 / 6.22	.255 / 6.48
I	.640 / 16.26	
J	.175 / 4.45	.217 / 5.51
K	.275 / 6.99	.285 / 7.24

ORDER CODE: ASI10677

CHARACTERISTICS $T_C = 25^\circ\text{C}$

SYMBOL	TEST CONDITIONS	MINIMUM	TYPICAL	MAXIMUM	UNITS
BV_{CES}	$I_C = 2.0$ mA	50			V
BV_{CEO}	$I_C = 15$ mA	30			V
BV_{EBO}	$I_E = 1.0$ mA	4.0			V
I_{CES}	$V_{CE} = 30$ V			0.5	mA
h_{FE}	$V_{CE} = 25$ V $I_C = 150$ mA	20		120	---
P_G	$V_{CE} = 25$ V $I_C = 150$ mA $f = 860$ MHz	11			dB
IMD_1	$P_{OUT} = 0.5$ W	-60			dBc

Mouser Electronics

Authorized Distributor

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